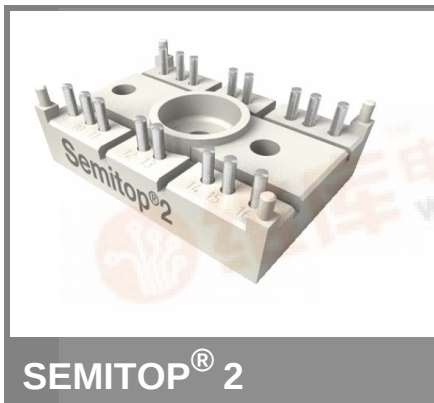


SK60GAL128



IGBT Module

SK60GAL128

SK60GAR128

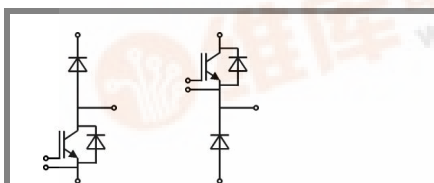
Preliminary Data

Features

- Compact design
- One screw mounting
- Heat transfer and isolation through direct copper bonded aluminium oxide ceramic (DCB)
- High short circuit capability
- SPT= Soft-Punch-Through technology
- $V_{ce,sat}$ with positive coefficient

Typical Applications

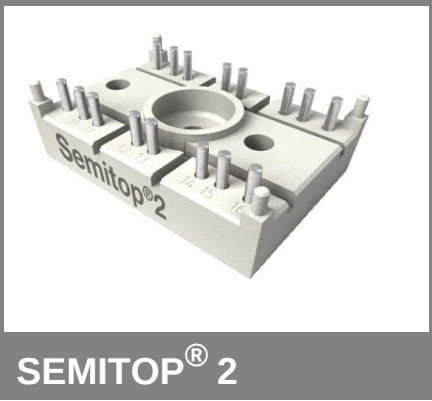
- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS



Absolute Maximum Ratings					$T_s = 25^\circ\text{C}$, unless otherwise specified	
Symbol	Conditions		Values	Units		
IGBT						
V_{CES}	$T_j = 25^\circ\text{C}$		1200	V		
I_C	$T_j = 125^\circ\text{C}$	$T_s = 25^\circ\text{C}$	63	A		
		$T_s = 80^\circ\text{C}$	44	A		
I_{CRM}	$I_{CRM} = 2 \times I_{Cnom}$		100	A		
V_{GES}			± 20	V		
t_{psc}	$V_{CC} = 600\text{ V}; V_{GE} \leq 20\text{ V}; T_j = 125^\circ\text{C}$ $V_{CES} < 1200\text{ V}$		10	μs		
Inverse Diode						
I_F	$T_j = 150^\circ\text{C}$	$T_s = 25^\circ\text{C}$	33	A		
		$T_s = 80^\circ\text{C}$	23	A		
I_{FRM}	$I_{FRM} = 2 \times I_{Fnom}$			A		
I_{FSM}	$t_p = 10\text{ ms}; \text{half sine wave}$	$T_j = 150^\circ\text{C}$	110	A		
Freewheeling Diode						
I_F	$T_j = 150^\circ\text{C}$	$T_{case} = 25^\circ\text{C}$	57	A		
		$T_{case} = 80^\circ\text{C}$	38	A		
I_{FRM}				A		
I_{FSM}	$t_p = 10\text{ ms}; \text{half sine wave}$	$T_j = 150^\circ\text{C}$	550	A		
Module						
$I_{t(RMS)}$				A		
T_{vj}			-40 ... +150	$^\circ\text{C}$		
T_{stg}			-40 ... +125	$^\circ\text{C}$		
V_{isol}	AC, 1 min.		2500	V		

Characteristics			T _s = 25 °C, unless otherwise specified			
Symbol	Conditions		min.	typ.	max.	Units
IGBT						
V _{GE(th)}	V _{GE} = V _{CE} , I _C = 2 mA		4,5	5,5	6,5	V
I _{CES}	V _{GE} = 0 V, V _{CE} = V _{CES} T _j = 25 °C T _j = 125 °C				0,1 0,2	mA mA
I _{GES}	V _{CE} = 0 V, V _{GE} = 20 V T _j = 25 °C T _j = 125 °C				200	nA nA
V _{CE0}	T _j = 25 °C T _j = 125 °C			1,1 1	1,3 1,2	V V
r _{CE}	V _{GE} = 15 V T _j = 25°C T _j = 125°C			16 18		mΩ mΩ
V _{CE(sat)}	I _{Cnom} = 50 A, V _{GE} = 15 V T _j = 25°C _{chiplev.} T _j = 125°C _{chiplev.}		1,7	1,9 1,9	2,3 2,3	V V
C _{ies} C _{oes} C _{res}	V _{CE} = 25, V _{GE} = 0 V f = 1 MHz			4,46 0,33 0,21		nF nF nF
t _{d(on)} t _r E _{on}	R _{Gon} = 15 Ω	V _{CC} = 600V I _{Cnom} = 50A		80 50 5,8		ns ns mJ
t _{d(off)} t _f E _{off}	R _{Goff} = 15 Ω	T _j = 125 °C V _{GE} =±15V		420 40 4,8		ns ns mJ
R _{th(j-s)}	per IGBT				0,6	K/W

SK60GAL128



IGBT Module

SK60GAL128

SK60GAR128

Preliminary Data

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- High short circuit capability
- SPT= Soft-Punch-Through technology
- $V_{ce,sat}$ with positive coefficient

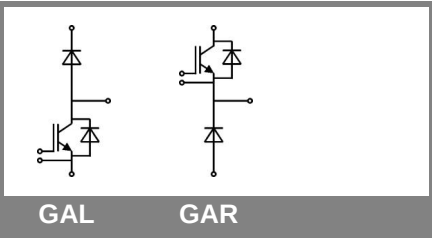
Typical Applications

- Switching (not for linear use)
- Inverter
- Switched mode power supplies
- UPS

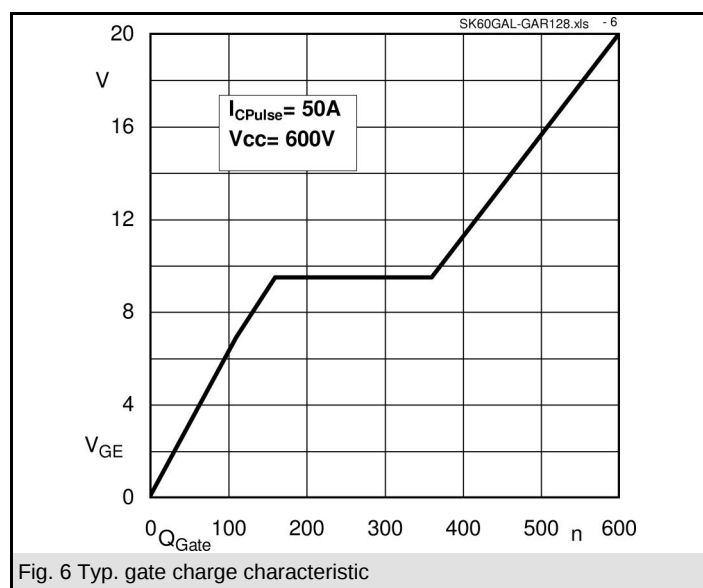
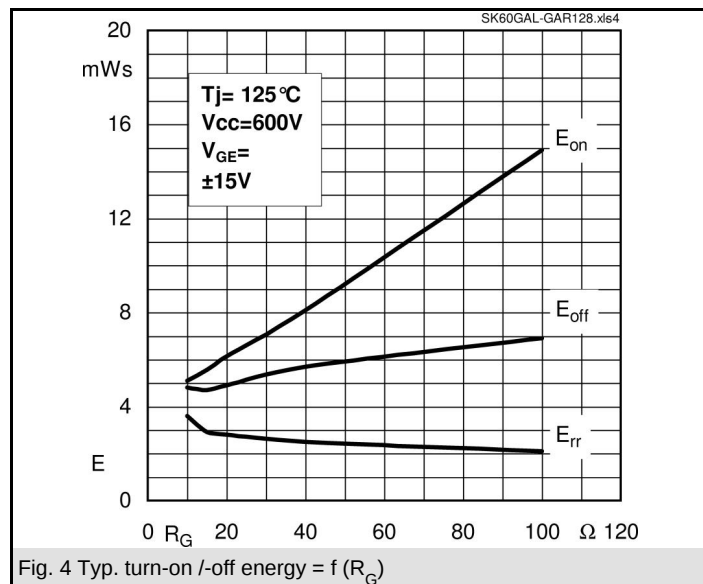
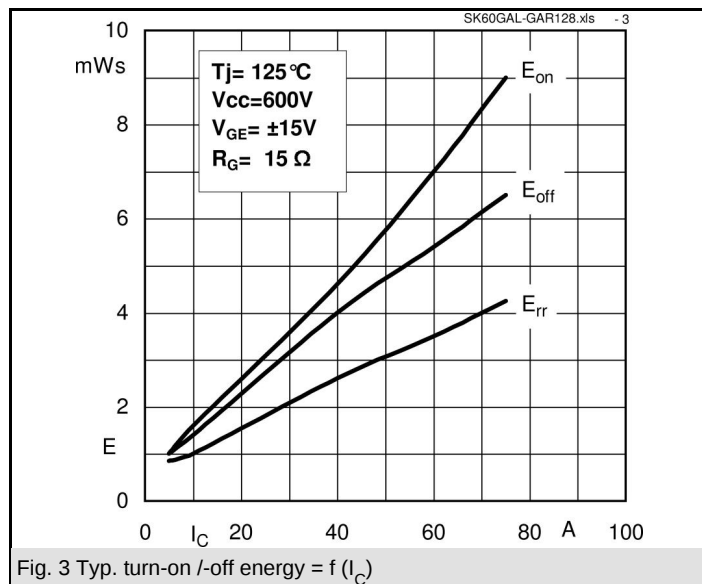
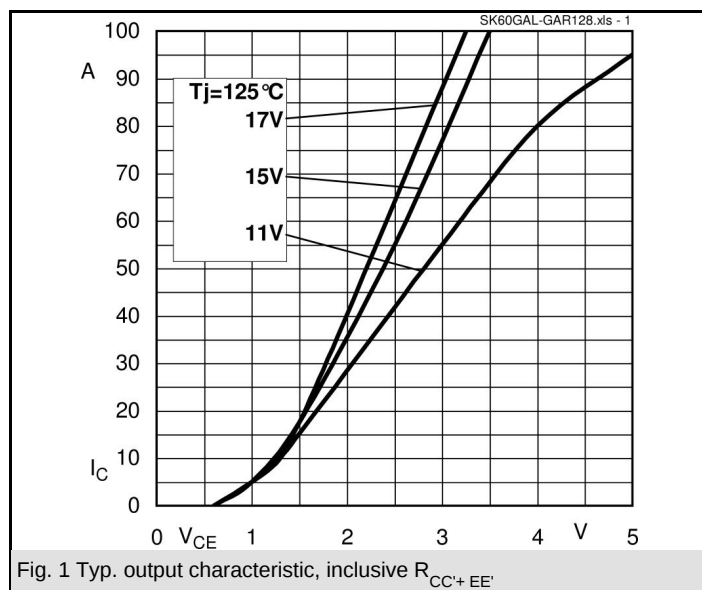
Characteristics						
Symbol	Conditions		min.	typ.	max.	Units
Inverse Diode						
V _F = V _{EC}	I _{Fnom} = 10 A; V _{GE} = 0 V	T _j = 25 °C _{chiplev.}	2	2,5	V	
		T _j = 125 °C _{chiplev.}	1,8	2,3	V	
V _{F0}		T _j = 125 °C	1,2		V	
r _F		T _j = 125 °C	62,7		mΩ	
I _{RRM}	I _{Fnom} = 10 A	T _j = 125 °C	12		A	
Q _{rr}	di/dt = -300 A/μs		1,8		μC	
E _{rr}	V _{CC} = 600V		0,4		mJ	
R _{th(j-s)D}	per diode			2,1	K/W	
Freewheeling Diode						
V _F = V _{EC}	I _{Fnom} = 50 A; V _{GE} = 0 V	T _j = 25 °C _{chiplev.}	2		V	
		T _j = 125 °C _{chiplev.}	1,8		V	
V _{F0}		T _j = 125 °C	1	1,2	V	
r _F		T _j = 125 °C	18	22	V	
I _{RRM}	I _{Fnom} = 50 A	T _j = 125 °C	40		A	
Q _{rr}	di/dt = -800 A/μs		8		μC	
E _{rr}	V _R =600V		2,3		mJ	
R _{th(j-s)FD}	per diode			0,9	K/W	
M _s	to heat sink M1			2	Nm	
w			21		g	

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

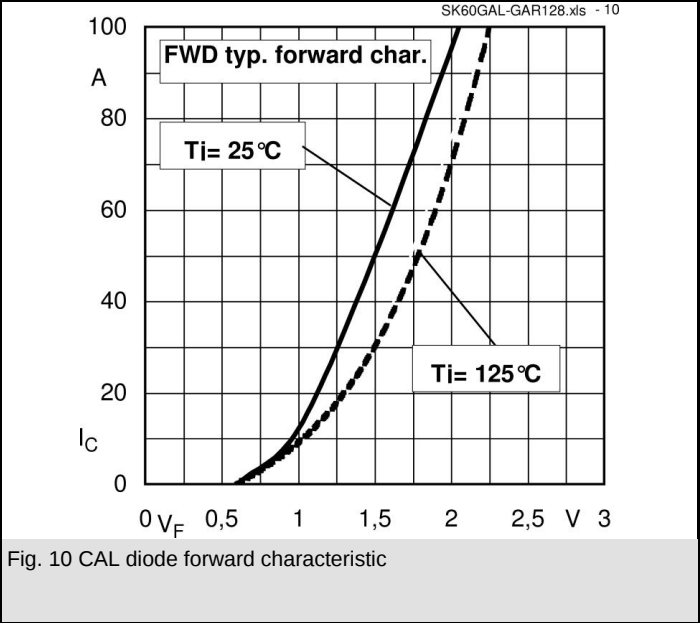
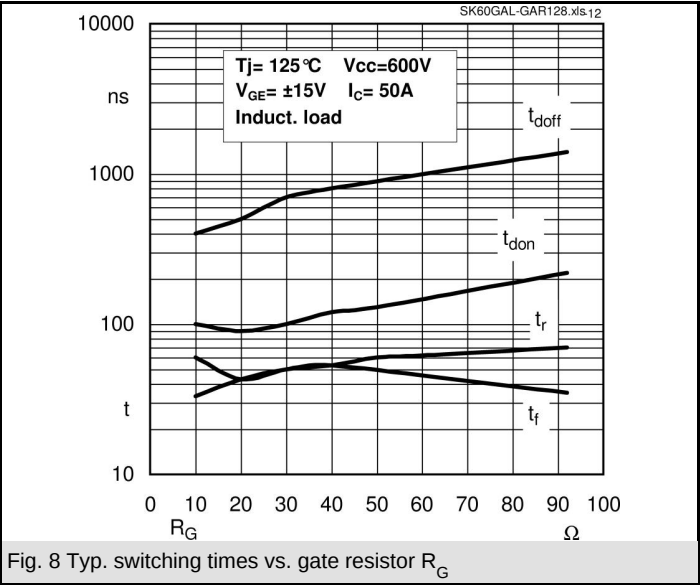
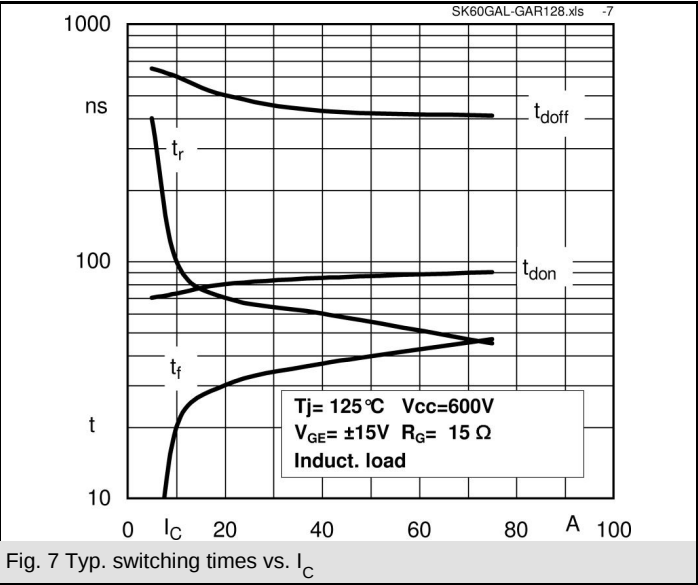
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SK60GAL128



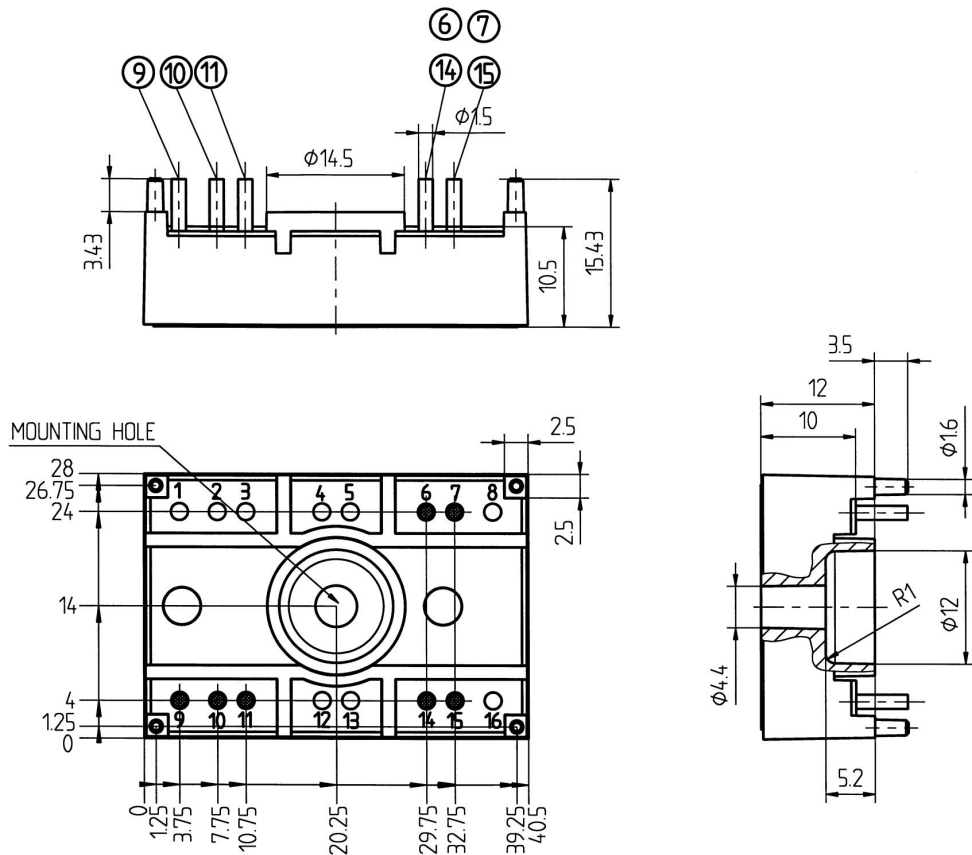
SK60GAL128



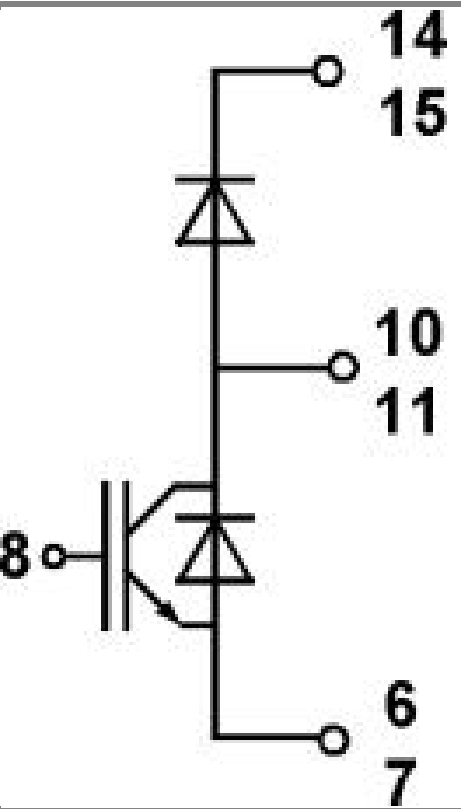
SK60GAL128

UL recognized file

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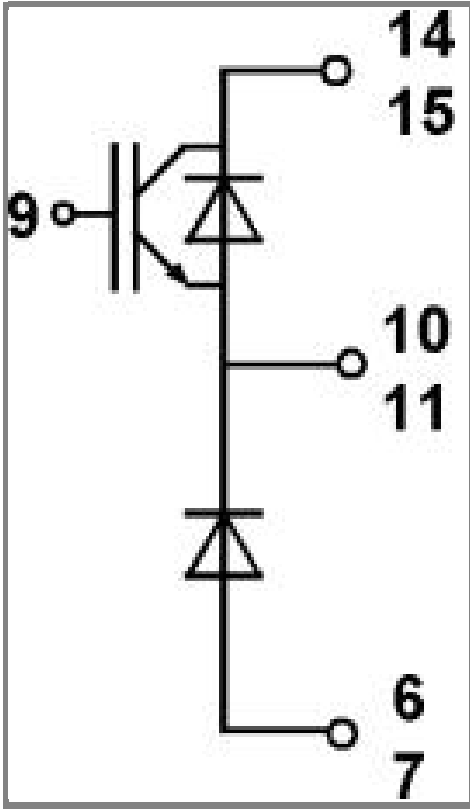


Case T18 (Suggested hole diameter, in the PCB, for solder pins and plastic mounting pins: 2mm)



Case T18

GAL



Case T18

GAR